

Supporting Information

Ce:(Lu,Sr)₃(Al,Si)₅O₁₂ transparent ceramics for high-power white LEDs/LDs with ultra-high luminance saturation threshold

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15. T. Nakano, Y. Kawakami, K. Uematsu, T. Ishigaki, K. Toda and M. Sato, *Journal of Luminescence*, 2009, **129**, 1654.

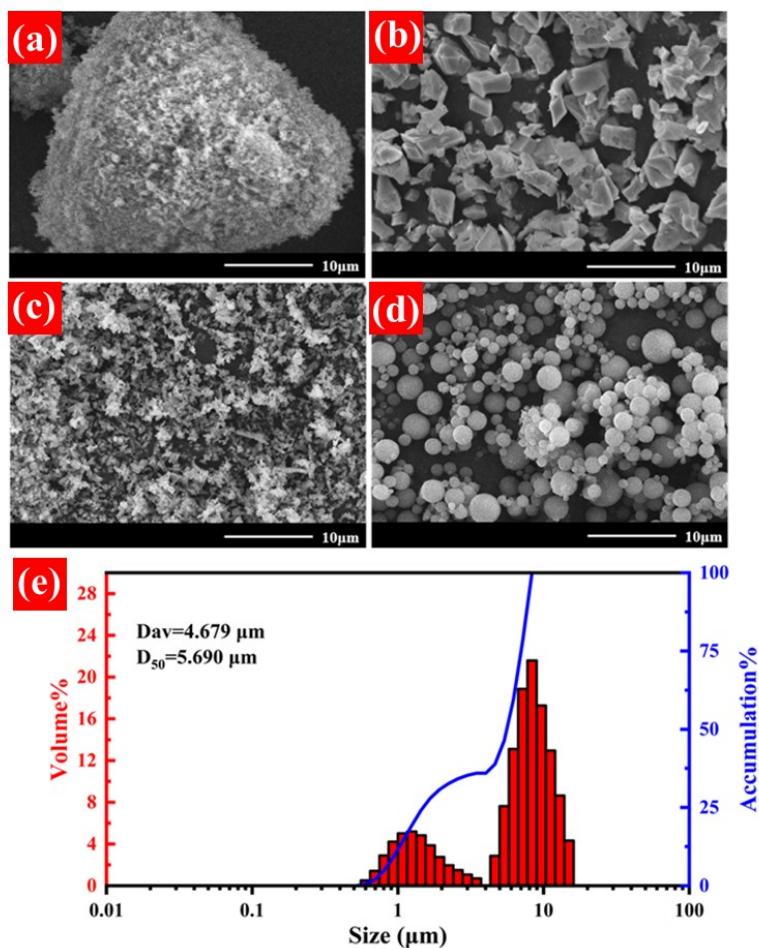


Fig. S1 SEM images of raw material powders: (a) Al₂O₃, (b) Lu₂O₃, (c) SrCO₃, (d) SiO₂. (e) Particle size distribution of Sr05 precursor powders

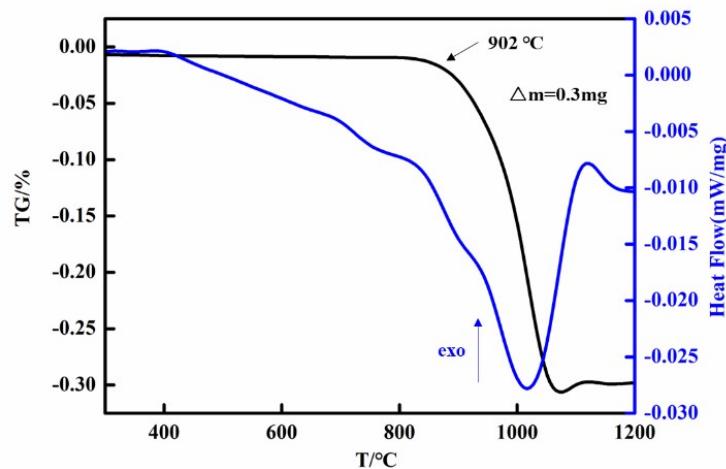


Fig. S2 TG/DSC curves of SrCO₃ powders

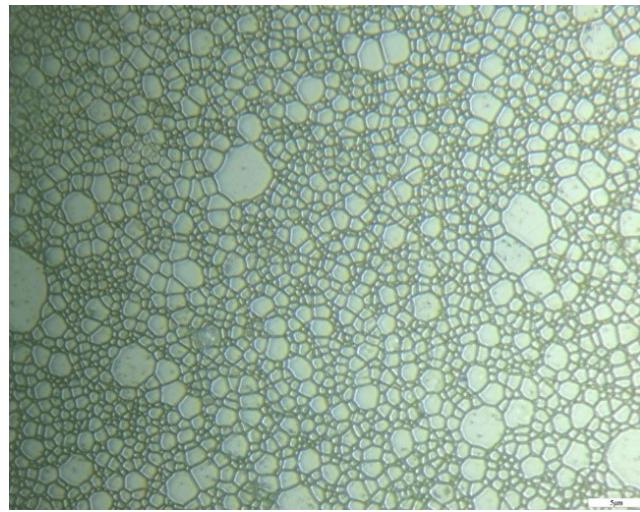


Fig. S3 Optical microscope image of Sr05 TC

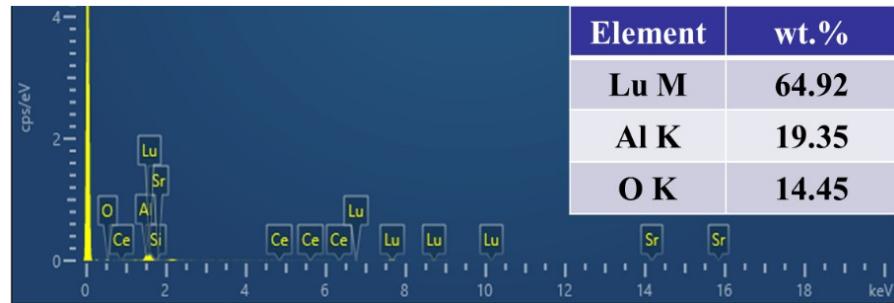


Fig. S4 EDS elemental mapping images of Sr05 TC

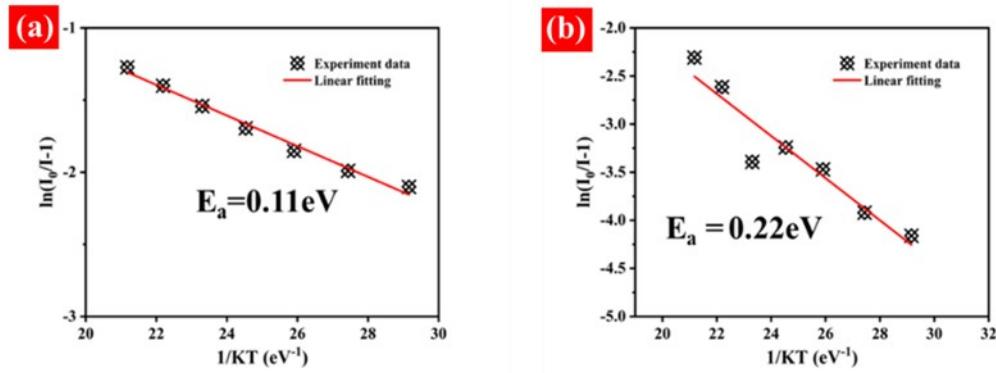


Fig. S5 The emission intensity and temperature Arrhenius fitting of (a) Sr00 and (b) Sr05 TC

$$I(T) = \frac{I_0}{1 + C \exp\left(\frac{-\Delta E}{KT}\right)} \quad Eq.S1$$

where I_0 and I_T represent the emission intensity at room temperature (RT) and operating temperature respectively, C is a constant and K is boltzmann constant (8.617×10^{-5} eV/K).

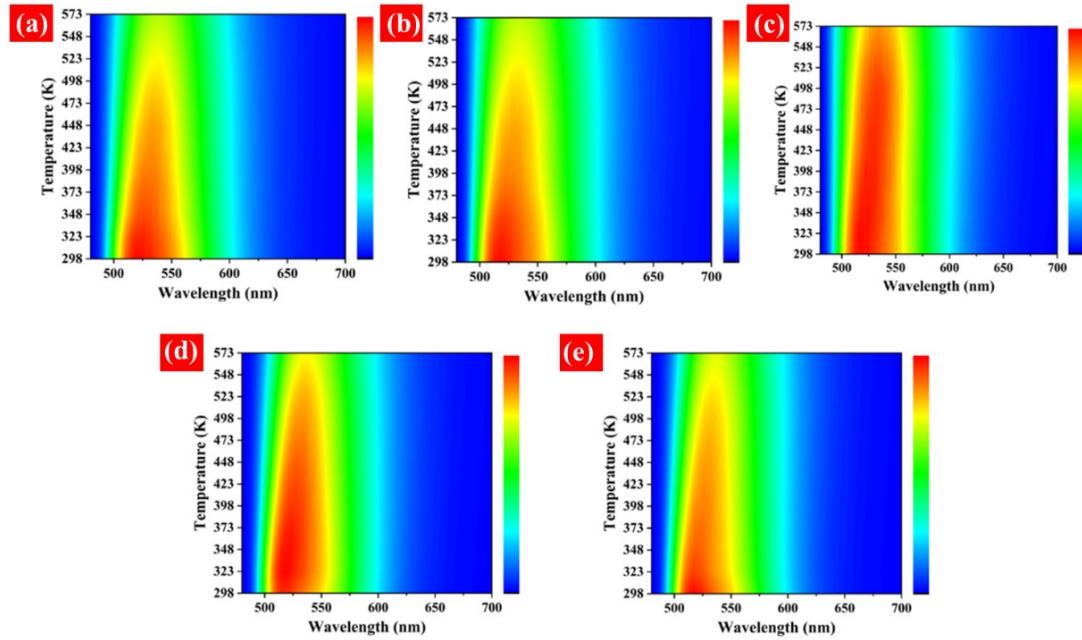


Fig. S6 Temperature-dependent PL spectra of (a) Sr00, (b) Sr025, (c) Sr05, (d) Sr075, (e) Sr10 TC under 460 nm excitation in the temperature range of 298–573 K

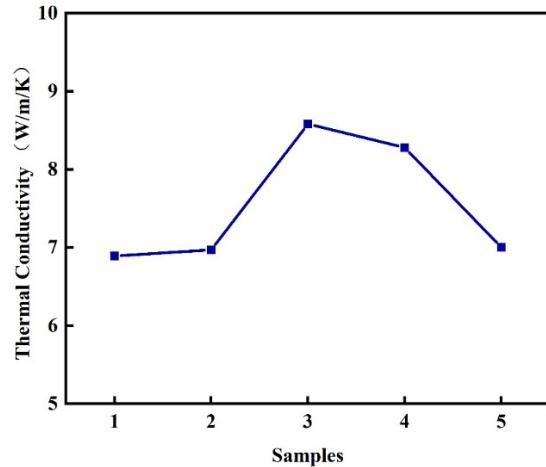


Fig. S7 Thermal conductivities of the Ce:LSASG at 50 °C

Table S2 The detailed CCT and CRI values of Ce: LSASG TCs

Sample	CRI	CCT
Sr00	48.5	5297
Sr025	47.7	5297
Sr05	48.1	5260
Sr075	47.3	5297
Sr10	46.1	5550

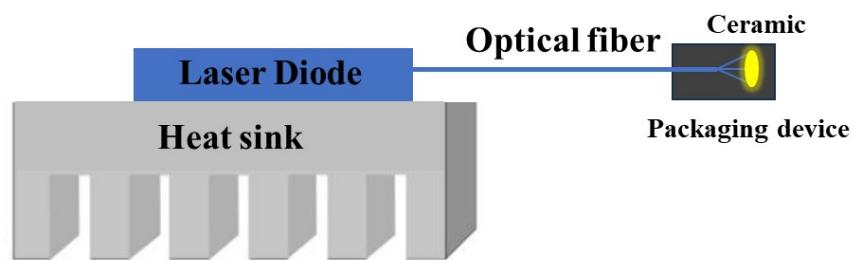


Fig. S8 A schematic of the designed white LD device

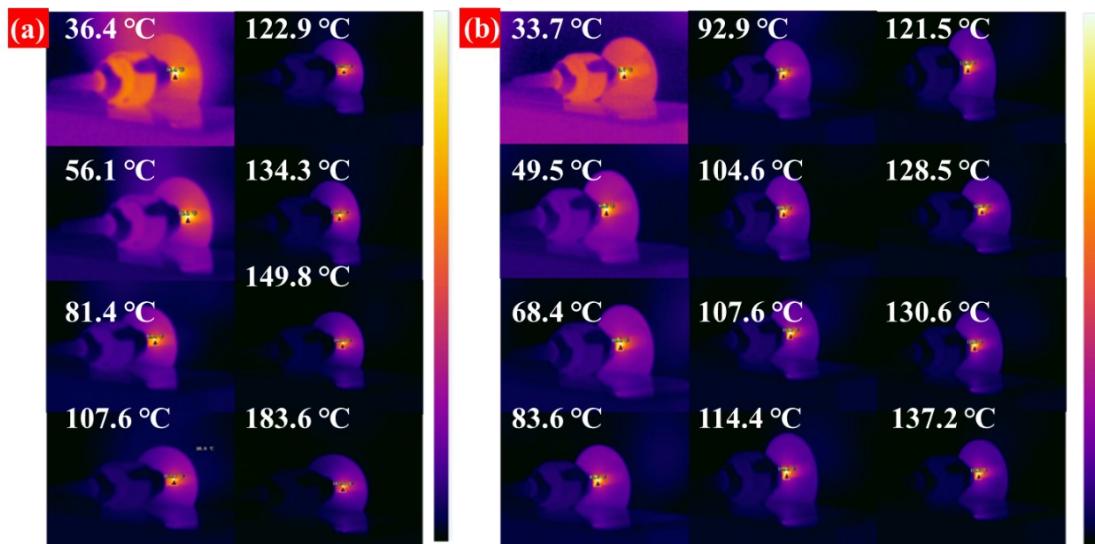


Fig. S9 Infrared thermal images and surface temperatures of (a) Sr05 and (b) Sr10 TC based LDs

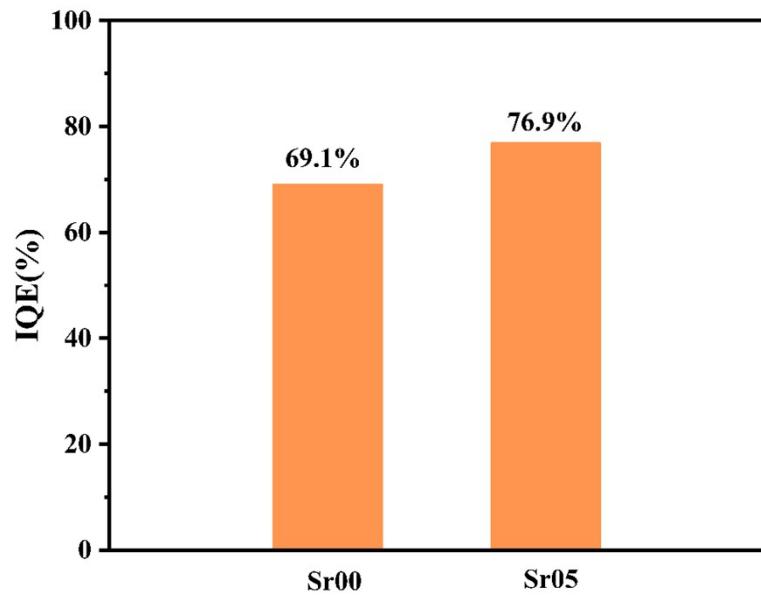


Fig.S10 IQE of Sr00 and Sr05 TCs

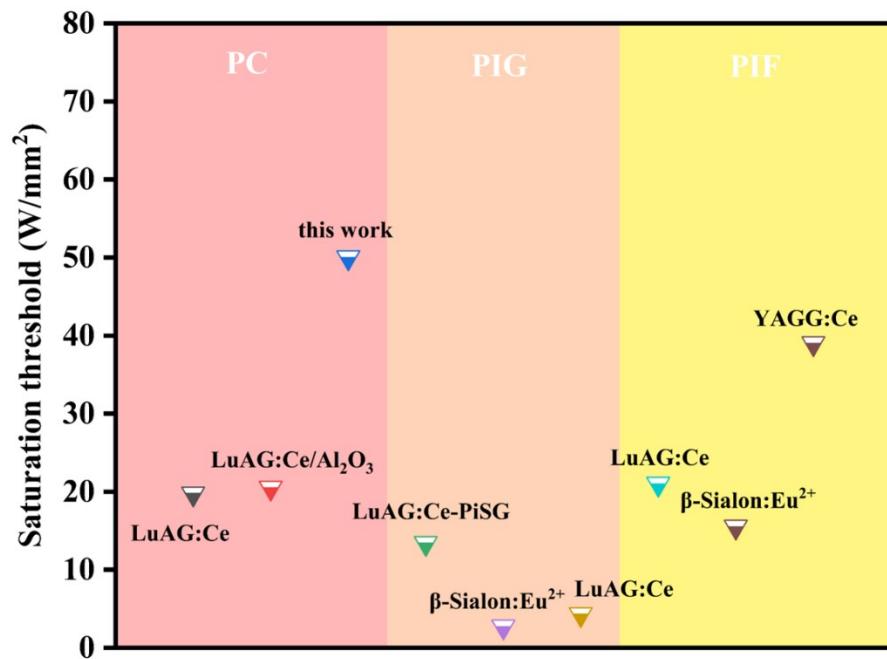


Fig. S11 The summarize of reported Saturation threshold of white LD source based on single structured phosphor ceramics